

2SD1418

Silicon NPN Epitaxial

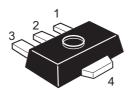
REJ03G0787-0200 (Previous ADE-208-1149) Rev.2.00 Aug.10.2005

Application

- Low frequency power amplifier
- Complementary pair with 2SB1025

Outline

RENESAS Package code: PLZZ0004CA-A (Package name: UPAK $^{\circledR}$)



- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (Flange)

*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	120	V
Collector to emitter voltage	V _{CEO}	80	V
Emitter to base voltage	V _{EBO}	5	V
Collector current	Ic	1	Α
Collector peak current	i _{C(peak)} *1	2	Α
Collector power dissipation	P _C * ²	1	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW ≤ 10 ms, Duty cycle ≤ 20%

2. Value on the alumina ceramic board (12.5 x 20 x 0.7 mm)

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

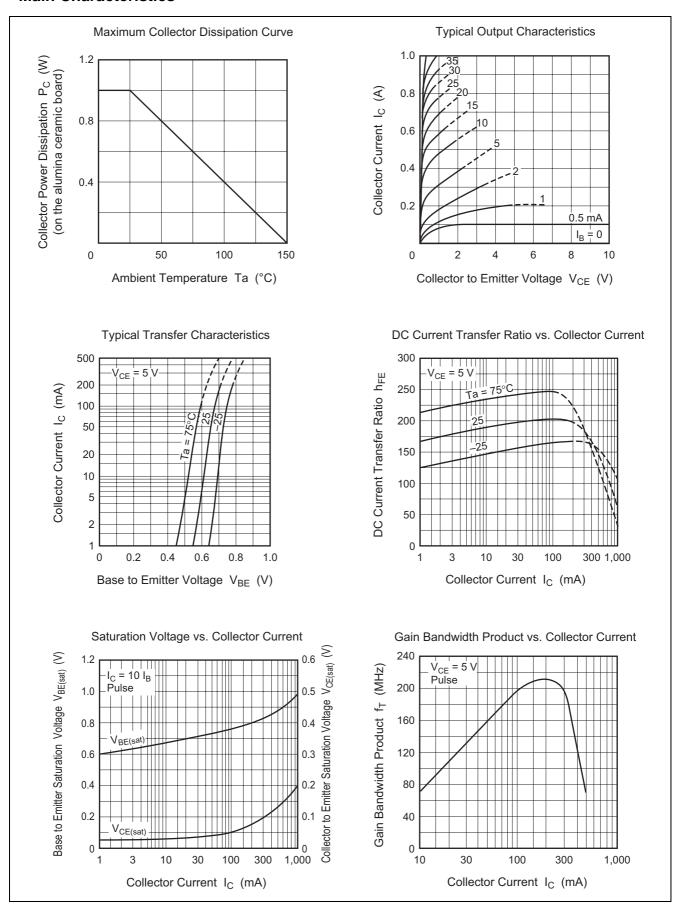
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	120	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	80	_	_	V	I_C = 1 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5		_	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I _{CBO}	_	_	10	μΑ	V _{CB} = 100 V, I _E = 0
DC current transfer ratio	h _{FE1} *1	60	_	320		$V_{EB} = 5 \text{ V}, I_{C} = 150 \text{ mA}*^{2}$
	h _{FE2}	30	_	_		$V_{CE} = 5 \text{ V}, I_{C} = 500 \text{ mA*}^2$
Collector to emitter saturation voltage	V _{CE(sat)}	_		1	V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}*^2$
Base to emitter voltage	V_{BE}	_		1.5	V	$V_{CE} = 5 \text{ V}, I_{C} = 150 \text{ mA}*^{2}$
Gain bandwidth product	f⊤	_	140	_	MHz	$V_{CE} = 5 \text{ V}, I_{C} = 150 \text{ mA*}^{2}$
Collector output capacitance	Cob	_	12	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$

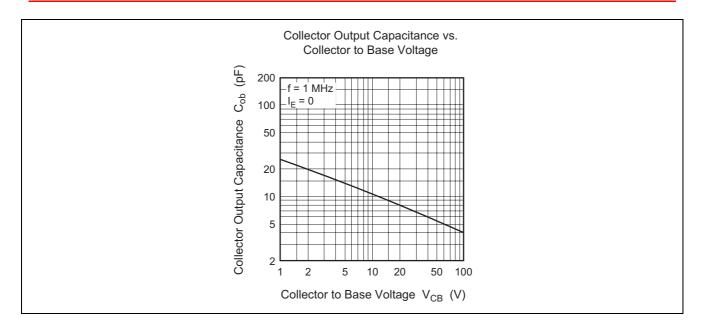
Notes: 1. The 2SD1418 is grouped by h_{FE1} as follows.

2. Pulse test

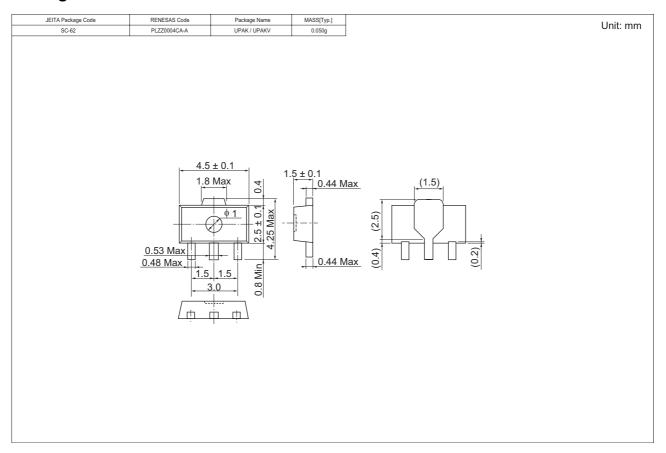
Mark	DA	DB	DC	
h _{FE1}	60 to 120	100 to 200	160 to 320	

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SD1418DATR-E	1000	φ 178 mm Reel, 12 mm Emboss Taping
2SD1418DBTR-E		
2SD1418DCTR-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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